



Welcome to [E-XFL.COM](#)

Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Active
Core Processor	ARM® Cortex®-A9
Number of Cores/Bus Width	4 Core, 32-Bit
Speed	852MHz
Co-Processors/DSP	Multimedia; NEON™ SIMD
RAM Controllers	LPDDR2, DDR3L, DDR3
Graphics Acceleration	Yes
Display & Interface Controllers	HDMI, Keypad, LCD, LVDS, MIPI/DSI, Parallel
Ethernet	10/100/1000Mbps (1)
SATA	SATA 3Gbps (1)
USB	USB 2.0 + PHY (3), USB 2.0 OTG + PHY (1)
Voltage - I/O	1.8V, 2.5V, 2.8V, 3.3V
Operating Temperature	-40°C ~ 125°C (TJ)
Security Features	ARM TZ, A-HAB, CAAM, CSU, SJC, SNVS
Package / Case	624-FBGA, FCBGA
Supplier Device Package	624-FCBGA (21x21)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx6qp4avt8aa

Table 2. i.MX 6DualPlus/6QuadPlus Modules List (continued)

Block Mnemonic	Block Name	Subsystem	Brief Description
PRE1 PRE2 PRE3 PRE4	Prefetch/Resolve Engine	Multimedia Peripherals	The PRE includes the Resolve engine, Prefetch engine, and Store engine 3 blocks. The PRE key features are: The Resolve engine supports: - GPU 32bpp 4x4 standard tile, 4x4 split tile, 4x4 super tile, 4x4 super split tile format. - GPU 16bpp 8x4 standard tile, 8x4 split tile, 8x4 super tile, 8x4 super split format. 32/16x4 block mode and scan mode. The prefetch engine supports: - Transfer of non-interleaved YUV422(NI422), non-interleaved YUV420(NI420), partial interleaved YUV422(PI422), and partial interleaved YUV420(PI420), inputs to interleaved YUV422. - Vertical flip function both in block mode and scan mode. In block mode, vertical flip function should complete with TPR module enable. 8bpp, 16bpp, 32bpp and 64bpp data format as generic data. - Transfer of non-interleaved YUV444(NI444), input to interleaved YUV444 output. The store Engine supports: 4/8/16 lines handshake modes with PRG.
PRG1 PRG2	Prefetch/Resolve Gasket	Multimedia Peripherals	The PRG is a digital core function which works as a gasket interface between the fabric and the IPU system. The primary function is to re-map the ARADDR from a frame-based address to a band-based address depending on the different ARIDs. The PRG also implements the handshake logic with the Prefetch Resolve Engine (PRE).
PMU	Power-Management Functions	Data Path	Integrated power management unit. Used to provide power to various SoC domains.
PWM-1 PWM-2 PWM-3 PWM-4	Pulse Width Modulation	Connectivity Peripherals	The pulse-width modulator (PWM) has a 16-bit counter and is optimized to generate sound from stored sample audio images and it can also generate tones. It uses 16-bit resolution and a 4x16 data FIFO to generate sound.
RAM 16 KB	Secure/non-secure RAM	Secured Internal Memory	Secure/non-secure Internal RAM, interfaced through the CAAM.
RAM 512 KB	Internal RAM	Internal Memory	Internal RAM, which is accessed through OCRAM memory controllers.
ROM 96 KB	Boot ROM	Internal Memory	Supports secure and regular Boot Modes. Includes read protection on 4K region for content protection
SATA	Serial ATA	Connectivity Peripherals	The SATA controller and PHY is a complete mixed-signal IP solution designed to implement SATA II, 3.0 Gbps HDD connectivity.

4 Electrical Characteristics

This section provides the device and module-level electrical characteristics for the i.MX 6DualPlus/6QuadPlus processors.

4.1 Chip-Level Conditions

This section provides the device-level electrical characteristics for the SoC. See [Table 3](#) for a quick reference to the individual tables and sections.

Table 3. i.MX 6DualPlus/6QuadPlus Chip-Level Conditions

For these characteristics, ...	Topic appears ...
Absolute Maximum Ratings	on page 20
FCPBGA Package Thermal Resistance	on page 21
Operating Ranges	on page 22
External Clock Sources	on page 24
Maximum Supply Currents	on page 26
Low Power Mode Supply Currents	on page 27
USB PHY Current Consumption	on page 29
SATA Typical Power Consumption	on page 29
PCIe 2.0 Maximum Power Consumption	on page 30
HDMI Maximum Power Consumption	on page 31

4.1.1 Absolute Maximum Ratings

CAUTION

Stresses beyond those listed under [Table 4](#) may affect reliability or cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the Operating Ranges or Parameters tables is not implied.

Table 4. Absolute Maximum Ratings

Parameter Description	Symbol	Min	Max	Unit
Core supply voltages	VDD_ARM_IN VDD_ARM23_IN VDD_SOC_IN	-0.3	1.5	V
Internal supply voltages	VDD_ARM_CAP VDD_ARM23_CAP VDD_SOC_CAP VDD_PU_CAP NVCC_PLL_OUT	-0.3	1.3	V
GPIO supply voltage	Supplies denoted as I/O supply	-0.5	3.6	V

Optionally LDO_SOC/VDD_SOC_CAP can be used to power the HDMI, PCIe, and SATA PHY's through external connections.

For additional information, see the i.MX 6DualPlus/6QuadPlus reference manual (IMX6DQPRM).

4.3.2 Regulators for Analog Modules

4.3.2.1 LDO_1P1 / NVCC_PLL_OUT

The LDO_1P1 regulator implements a programmable linear-regulator function from VDD_HIGH_IN (see [Table 6](#) for minimum and maximum input requirements). Typical Programming Operating Range is 1.0 V to 1.2 V with the nominal default setting as 1.1 V. The LDO_1P1 supplies the 24 MHz oscillator, PLLs, and USB PHY. A programmable brown-out detector is included in the regulator that can be used by the system to determine when the load capability of the regulator is being exceeded to take the necessary steps. Current-limiting can be enabled to allow for in-rush current requirements during start-up, if needed. Active-pull-down can also be enabled for systems requiring this feature.

For information on external capacitor requirements for this regulator, see the Hardware Development Guide for i.MX 6Quad, 6Dual, 6DualLite, 6Solo Families of Applications Processors (IMX6DQ6SDLHDG).

For additional information, see the i.MX 6DualPlus/6QuadPlus reference manual (IMX6DQPRM).

4.3.2.2 LDO_2P5 / VDDHIGH_CAP

The LDO_2P5 module implements a programmable linear-regulator function from VDD_HIGH_IN (see [Table 6](#) for min and max input requirements). Typical Programming Operating Range is 2.25 V to 2.75 V with the nominal default setting as 2.5 V. The LDO_2P5 supplies the eFuses, PLLs, and USB PHY. Optionally it can be used to supply the HDMI, LVDS, MIPI, PCIe, and SATA PHY's through external connections. A programmable brown-out detector is included in the regulator that can be used by the system to determine when the load capability of the regulator is being exceeded, to take the necessary steps. Current-limiting can be enabled to allow for in-rush current requirements during start-up, if needed. Active-pull-down can also be enabled for systems requiring this feature. An alternate self-biased low-precision weak-regulator is included that can be enabled for applications needing to keep the output voltage alive during low-power modes where the main regulator driver and its associated global bandgap reference module are disabled. The output of the weak-regulator is not programmable and is a function of the input supply as well as the load current. Typically, with a 3 V input supply the weak-regulator output is 2.525 V and its output impedance is approximately 40 Ω .

For information on external capacitor requirements for this regulator, see the Hardware Development Guide for i.MX 6Quad, 6Dual, 6DualLite, 6Solo Families of Applications Processors (IMX6DQ6SDLHDG).

For additional information, see the i.MX 6DualPlus/6QuadPlus reference manual (IMX6DQPRM).

4.8 Output Buffer Impedance Parameters

This section defines the I/O impedance parameters of the i.MX 6DualPlus/6QuadPlus processors for the following I/O types:

- General Purpose I/O (GPIO)
- Double Data Rate I/O (DDR) for LPDDR2, and DDR3 modes
- LVDS I/O
- MLB I/O

NOTE

GPIO and DDR I/O output driver impedance is measured with “long” transmission line of impedance Z_{tl} attached to I/O pad and incident wave launched into transmission line. R_{pu}/R_{pd} and Z_{tl} form a voltage divider that defines specific voltage of incident wave relative to OVDD. Output driver impedance is calculated from this voltage divider (see [Figure 9](#)).

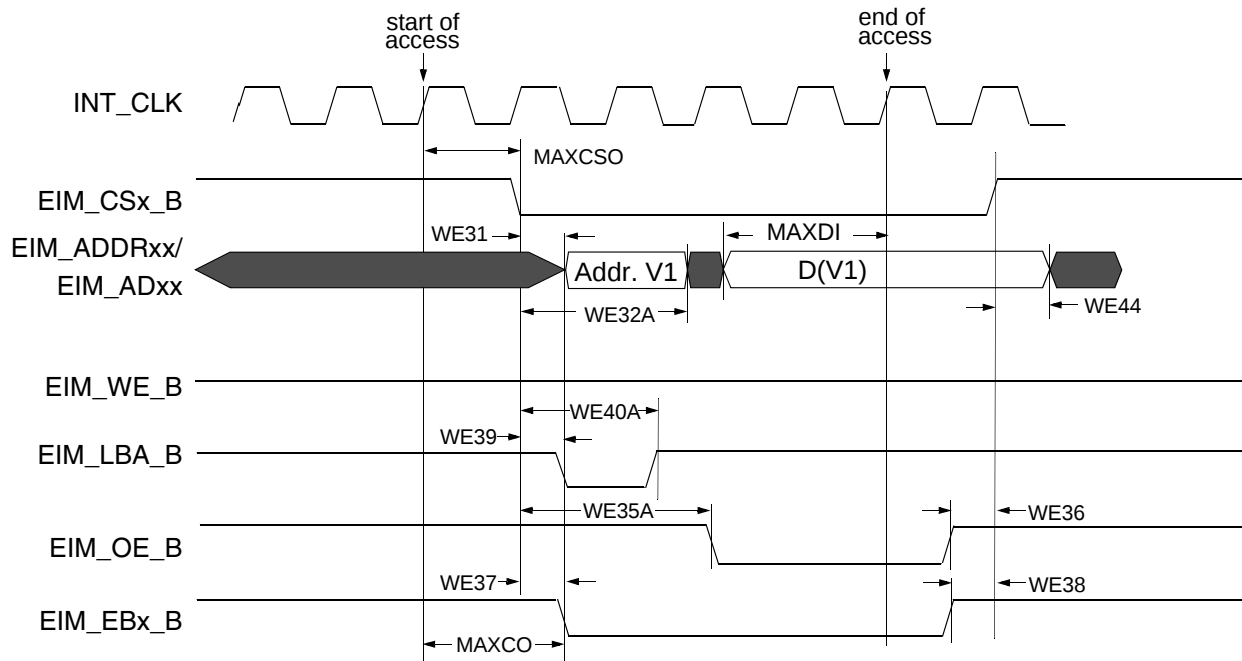


Figure 19. Asynchronous A/D Muxed Read Access (RWSC = 5)

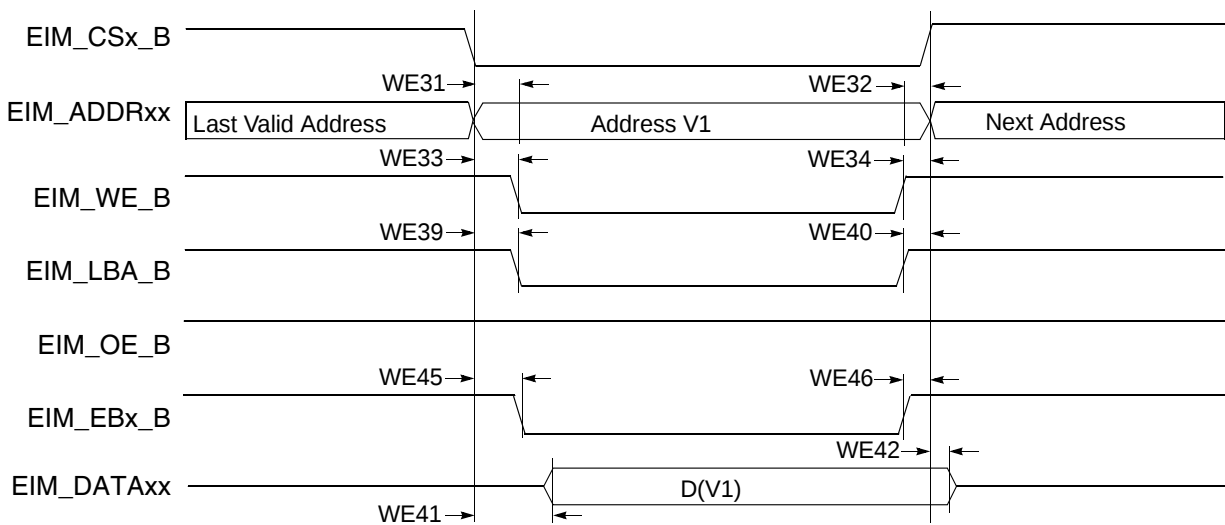


Figure 20. Asynchronous Memory Write Access

² In this table:

- t means clock period from axi_clk frequency.
- CSA means register setting for WCSA when in write operations or RCSA when in read operations.
- CSN means register setting for WCSN when in write operations or RCSN when in read operations.
- ADVN means register setting for WADV when in write operations or RADVN when in read operations.
- ADVA means register setting for WADVA when in write operations or RADVA when in read operations.

4.9.4 DDR SDRAM Specific Parameters (DDR3/DDR3L and LPDDR2)

4.9.4.1 DDR3/DDR3L Parameters

Figure 24 shows the DDR3/DDR3L basic timing diagram. The timing parameters for this diagram appear in Table 42.

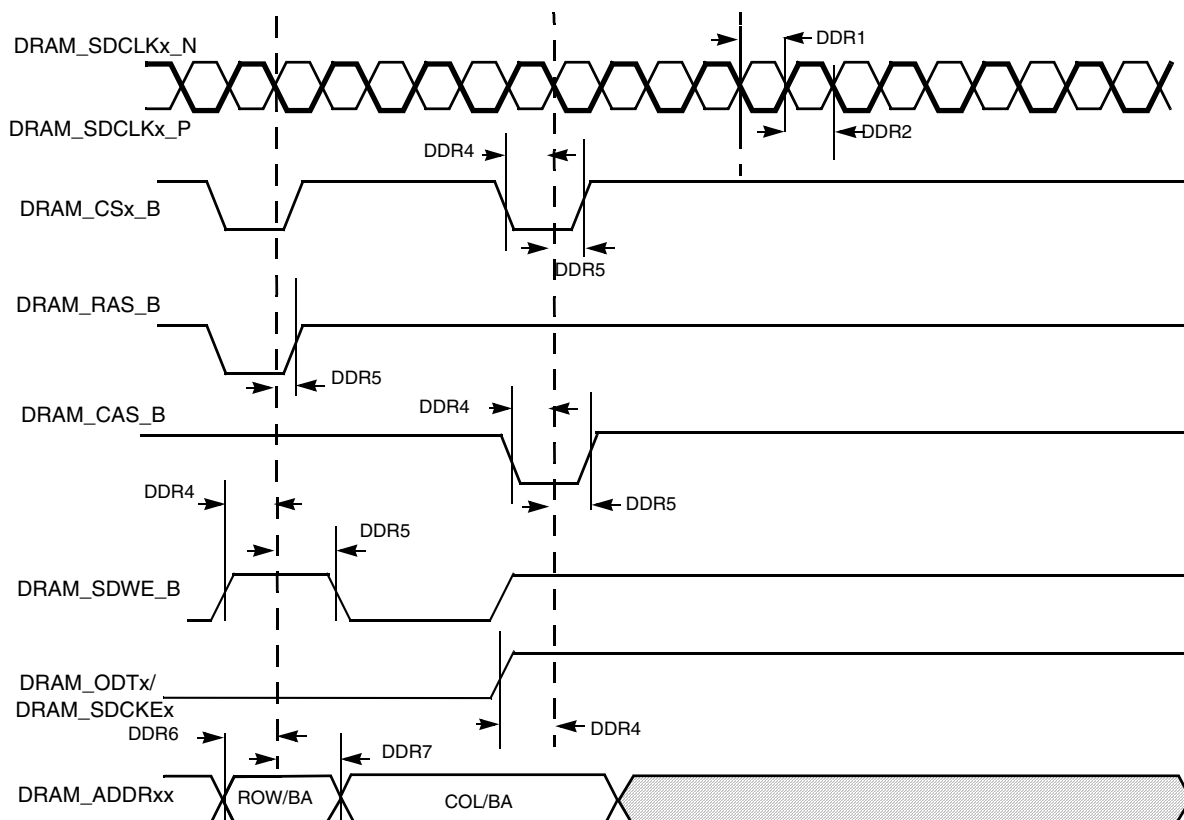


Figure 24. DDR3/DDR3L Command and Address Timing Diagram

Table 42. DDR3/DDR3L Command and Address Timing Parameter

ID	Parameter ^{1,2}	Symbol	CK = 532 MHz		Unit
			Min	Max	
DDR1	DRAM_SDCLKx_P clock high-level width	tCH	0.47	0.53	tCK
DDR2	DRAM_SDCLKx_P clock low-level width	tCL	0.47	0.53	tCK

Table 45. LPDDR2 Command and Address Timing Parameters

ID	Parameter ^{1,2}	Symbol	CK = 400 MHz		Unit
			Min	Max	
LP1	DRAM_SDCLKx_P clock high-level width	tCH	0.45	0.55	tCK
LP2	DRAM_SDCLKx_P clock low-level width	tCL	0.45	0.55	tCK
LP3	DRAM_CSx_B, DRAM_ADDRx setup time	tIS	390	—	ps
LP4	DRAM_CSx_B, DRAM_ADDRx hold time	tIH	390	—	ps
LP3	DRAM_ADDRx setup time	tIS	390	—	ps
LP4	DRAM_ADDRx hold time	tIH	390	—	ps

¹ All measurements are in reference to Vref level.

² Measurements were completed using balanced load and a 25 Ω resistor from outputs to DRAM_VREF.

Figure 28 shows the LPDDR2 write timing diagram. The timing parameters for this diagram appear in Table 46.

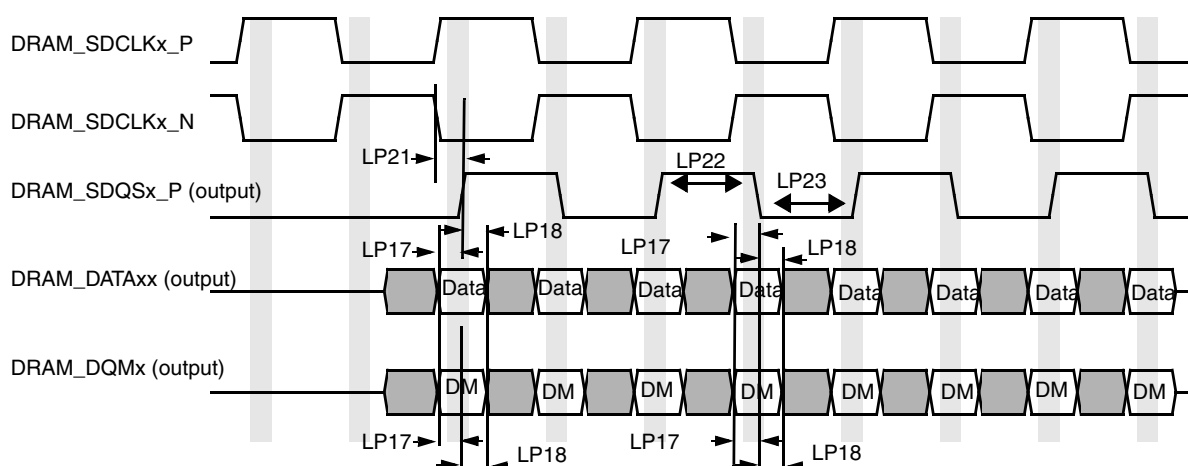


Figure 28. LPDDR2 Write Cycle

Table 46. LPDDR2 Write Cycle

ID	Parameter ^{1,2,3}	Symbol	CK = 400 MHz		Unit
			Min	Max	
LP17	DRAM_DATAxx and DRAM_DQMx setup time to DRAM_SDQSx_P (differential strobe)	tDS	370	—	ps
LP18	DRAM_DATAxx and DRAM_DQMx hold time to DRAM_SDQSx_P (differential strobe)	tDH	370	—	ps
LP21	DRAM_SDQSx_P latching rising transitions to associated clock edges	tDQSS	0.75	1.25	tCK

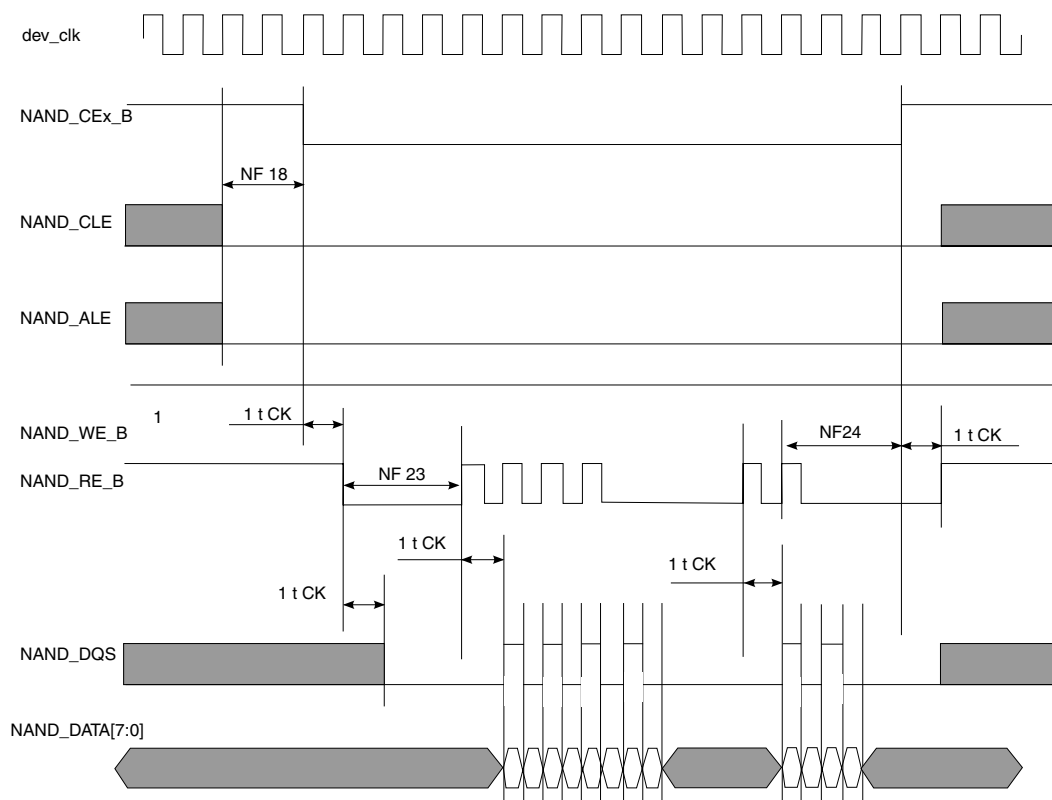


Figure 40. Samsung Toggle Mode Data Read Timing

Table 50. Samsung Toggle Mode Timing Parameters¹

ID	Parameter	Symbol	Timing T = GPML Clock Cycle		Unit
			Min	Max	
NF1	NAND_CLE setup time	tCLS	$(AS + DS) \times T - 0.12$ [see ^{2,3}]		—
NF2	NAND_CLE hold time	tCLH	$DH \times T - 0.72$ [see ²]		—
NF3	NAND_CEx_B setup time	tCS	$(AS + DS) \times T - 0.58$ [see ^{3,2}]		—
NF4	NAND_CEx_B hold time	tCH	$DH \times T - 1$ [see ²]		—
NF5	NAND_WE_B pulse width	tWP	$DS \times T$ [see ²]		—
NF6	NAND_ALE setup time	tALS	$(AS + DS) \times T - 0.49$ [see ^{3,2}]		—
NF7	NAND_ALE hold time	tALH	$DH \times T - 0.42$ [see ²]		—
NF8	Command/address NAND_DATAxx setup time	tCAS	$DS \times T - 0.26$ [see ²]		—
NF9	Command/address NAND_DATAxx hold time	tCAH	$DH \times T - 1.37$ [see ²]		—
NF18	NAND_CEx_B access time	tCE	$CE_DELAY \times T$ [see ^{4,2}]	—	ns
NF22	clock period	tCK	—	—	ns
NF23	preamble delay	tPRE	$PRE_DELAY \times T$ [see ^{5,2}]	—	ns
NF24	postamble delay	tPOST	$POST_DELAY \times T + 0.43$ [see ²]	—	ns

4.11.3 Enhanced Serial Audio Interface (ESAI) Timing Parameters

The ESAI consists of independent transmitter and receiver sections, each section with its own clock generator. Table 53 shows the interface timing values. The number field in the table refers to timing signals found in Figure 43 and Figure 44.

Table 53. Enhanced Serial Audio Interface (ESAI) Timing

ID	Parameter ^{1,2}	Symbol	Expression ²	Min	Max	Condition ³	Unit
62	Clock cycle ⁴	t_{SSICC}	$4 \times T_C$ $4 \times T_C$	30.0 30.0	— —	i ck i ck	ns
63	Clock high period: • For internal clock • For external clock	— —	$2 \times T_C - 9.0$ $2 \times T_C$	6 15	— —	— —	ns
64	Clock low period: • For internal clock • For external clock	— —	$2 \times T_C - 9.0$ $2 \times T_C$	6 15	— —	— —	ns
65	ESAI_RX_CLK rising edge to ESAI_RX_FS out (bl) high	— —	— —	— —	19.0 7.0	x ck i ck a	ns
66	ESAI_RX_CLK rising edge to ESAI_RX_FS out (bl) low	— —	— —	— —	19.0 7.0	x ck i ck a	ns
67	ESAI_RX_CLK rising edge to ESAI_RX_FS out (wr) high ⁵	— —	— —	— —	19.0 9.0	x ck i ck a	ns
68	ESAI_RX_CLK rising edge to ESAI_RX_FS out (wr) low ⁵	— —	— —	— —	19.0 9.0	x ck i ck a	ns
69	ESAI_RX_CLK rising edge to ESAI_RX_FS out (wl) high	— —	— —	— —	19.0 6.0	x ck i ck a	ns
70	ESAI_RX_CLK rising edge to ESAI_RX_FSout (wl) low	— —	— —	— —	17.0 7.0	x ck i ck a	ns
71	Data in setup time before ESAI_RX_CLK (serial clock in synchronous mode) falling edge	— —	— —	12.0 19.0	— —	x ck i ck	ns
72	Data in hold time after ESAI_RX_CLK falling edge	— —	— —	3.5 9.0	— —	x ck i ck	ns
73	ESAI_RX_FS input (bl, wr) high before ESAI_RX_CLK falling edge ⁵	— —	— —	2.0 19.0	— —	x ck i ck a	ns
74	ESAI_RX_FS input (wl) high before ESAI_RX_CLK falling edge	— —	— —	2.0 19.0	— —	x ck i ck a	ns
75	ESAI_RX_FS input hold time after ESAI_RX_CLK falling edge	— —	— —	2.5 8.5	— —	x ck i ck a	ns
78	ESAI_TX_CLK rising edge to ESAI_TX_FS out (bl) high	— —	— —	— —	19.0 8.0	x ck i ck	ns
79	ESAI_TX_CLK rising edge to ESAI_TX_FS out (bl) low	— —	— —	— —	20.0 10.0	x ck i ck	ns
80	ESAI_TX_CLK rising edge to ESAI_TX_FS out (wr) high ⁵	— —	— —	— —	20.0 10.0	x ck i ck	ns

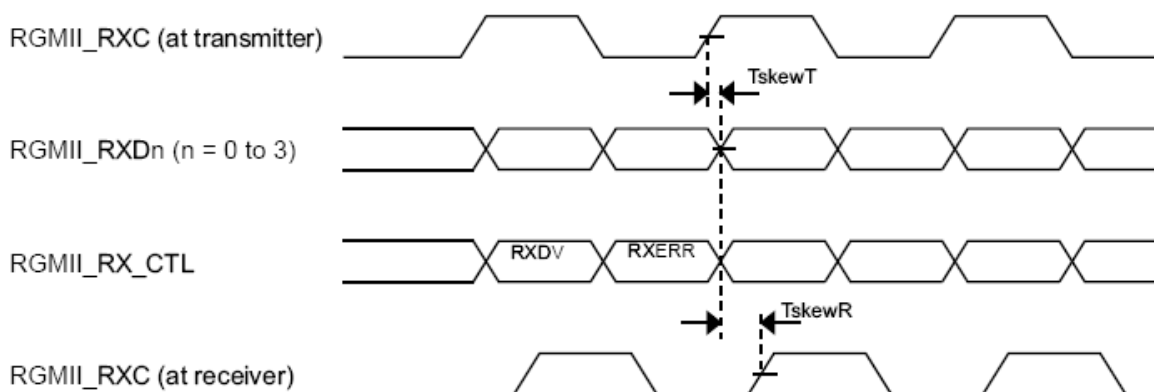


Figure 54. RGMII Receive Signal Timing Diagram Original

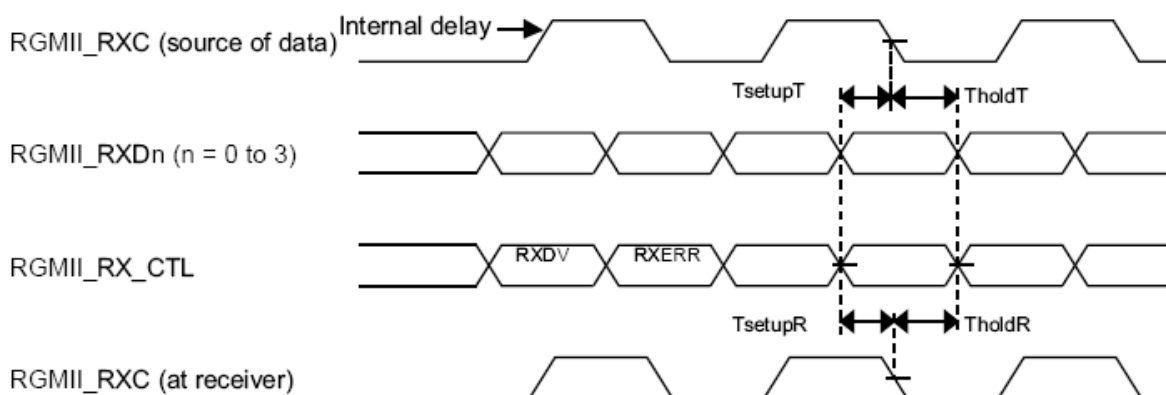


Figure 55. RGMII Receive Signal Timing Diagram with Internal Delay

4.11.6 Flexible Controller Area Network (FlexCAN) AC Electrical Specifications

The Flexible Controller Area Network (FlexCAN) module is a communication controller implementing the CAN protocol according to the CAN 2.0B protocol specification. The processor has two CAN modules available for systems design. Tx and Rx ports for both modules are multiplexed with other I/O pins. See the IOMUXC chapter of the i.MX 6DualPlus/6QuadPlus reference manual (IMX6DQPRM) to see which pins expose Tx and Rx pins; these ports are named FLEXCAN_TX and FLEXCAN_RX, respectively.

4.11.7 HDMI Module Timing Parameters

4.11.7.1 Latencies and Timing Information

Power-up time (time between TX_PWRON assertion and TX_READY assertion) for the HDMI 3D Tx PHY while operating with the slowest input reference clock supported (13.5 MHz) is 3.35 ms.

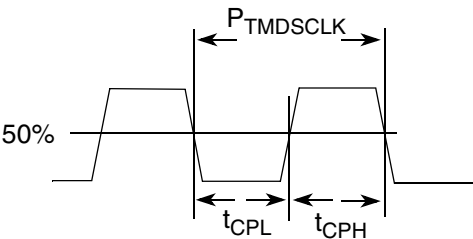


Figure 59. TMDSClock Signal Definitions

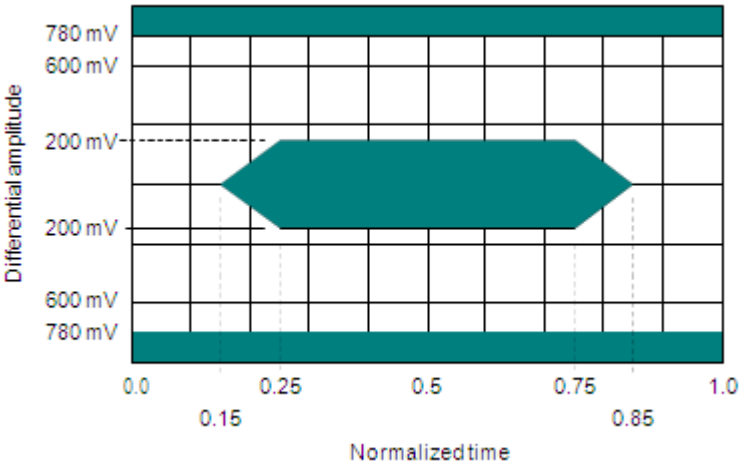


Figure 60. Eye Diagram Mask Definition for HDMI Driver Signal Specification at TP1

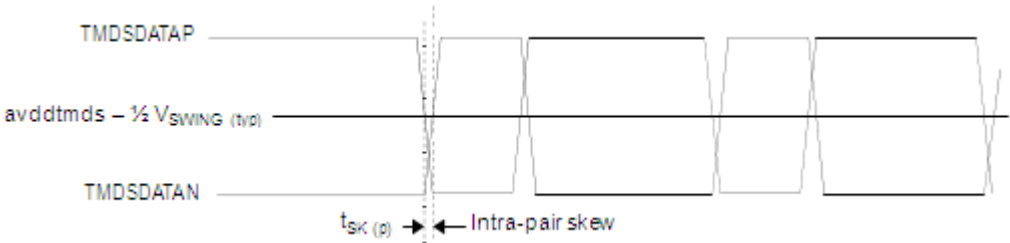


Figure 61. Intra-Pair Skew Definition

Table 68. Video Signal Cross-Reference (continued)

i.MX 6DualPlus/6QuadPlus	LCD							Comment ^{1,2}
Port Name (x = 0, 1)	RGB, Signal Name (General)	RGB/TV Signal Allocation (Example)						
		16-bit RGB	18-bit RGB	24 Bit RGB	8-bit YCrCb ³	16-bit YCrCb	20-bit YCrCb	
IPUx_DIx_PIN04	—							Additional frame/row synchronous signals with programmable timing
IPUx_DIx_PIN05	—							
IPUx_DIx_PIN06	—							
IPUx_DIx_PIN07	—							
IPUx_DIx_PIN08	—							
IPUx_DIx_D0_CS	—							—
IPUx_DIx_D1_CS	—							Alternate mode of PWM output for contrast or brightness control
IPUx_DIx_PIN11	—							—
IPUx_DIx_PIN12	—							—
IPUx_DIx_PIN13	—							Register select signal
IPUx_DIx_PIN14	—							Optional RS2
IPUx_DIx_PIN15	DRDY/DV							Data validation/blank, data enable
IPUx_DIx_PIN16	—							Additional data synchronous signals with programmable features/timing
IPUx_DIx_PIN17	Q							

¹ Signal mapping (both data and control/synchronization) is flexible. The table provides examples.

² Restrictions for ports IPUx_DISPx_DAT00 through IPUx_DISPx_DAT23 are as follows:

- A maximum of three continuous groups of bits can be independently mapped to the external bus. Groups must not overlap.
- The bit order is expressed in each of the bit groups, for example, B[0] = least significant blue pixel bit.

³ This mode works in compliance with recommendation ITU-R BT.656. The timing reference signals (frame start, frame end, line start, and line end) are embedded in the 8-bit data bus. Only video data is supported, transmission of non-video related data during blanking intervals is not supported.

NOTE

Table 68 provides information for both the DISP0 and DISP1 ports. However, DISP1 port has reduced pinout depending on IOMUXC configuration and therefore may not support all configurations. See the IOMUXC table for details.

4.11.10.5 IPU Display Interface Timing

The IPU Display Interface supports two kinds of display accesses: synchronous and asynchronous. There are two groups of external interface pins to provide synchronous and asynchronous controls.

4.11.10.5.1 Synchronous Controls

The synchronous control changes its value as a function of a system or of an external clock. This control has a permanent period and a permanent waveform.

Table 73. Electrical and Timing Information (continued)

Symbol	Parameters	Test Conditions	Min	Typ	Max	Unit
t_{CDC}	DDR CLK duty cycle	$t_{CDC} = t_{CPH} / P_{DDRCLK}$	—	50	—	%
t_{CPH}	DDR CLK high time	—	—	1	—	UI
t_{CPL}	DDR CLK low time	—	—	1	—	UI
—	DDR CLK / DATA Jitter	—	—	75	—	ps pk-pk
$t_{SKEW[PN]}$	Intra-Pair (Pulse) skew	—	—	0.075	—	UI
$t_{SKEW[TX]}$	Data to Clock Skew	—	0.350	—	0.650	UI
t_r	Differential output signal rise time	20% to 80%, $R_L = 50 \Omega$	150	—	0.3UI	ps
t_f	Differential output signal fall time	20% to 80%, $R_L = 50 \Omega$	150	—	0.3UI	ps
$\Delta V_{CMTX(HF)}$	Common level variation above 450 MHz	$80 \Omega \leq R_L \leq 125 \Omega$	—	—	15	mV _{rms}
$\Delta V_{CMTX(LF)}$	Common level variation between 50 MHz and 450 MHz	$80 \Omega \leq R_L \leq 125 \Omega$	—	—	25	mV _p
LP Line Drivers AC Specifications						
t_{rip}, t_{flp}	Single ended output rise/fall time	15% to 85%, $C_L < 70$ pF	—	—	25	ns
t_{reo}	—	30% to 85%, $C_L < 70$ pF	—	—	35	ns
$\delta V / \delta t_{SR}$	Signal slew rate	15% to 85%, $C_L < 70$ pF	—	—	120	mV/ns
C_L	Load capacitance	—	0	—	70	pF
HS Line Receiver AC Specifications						
$t_{SETUP[RX]}$	Data to Clock Receiver Setup time	—	0.15	—	—	UI
$t_{HOLD[RX]}$	Clock to Data Receiver Hold time	—	0.15	—	—	UI
$\Delta V_{CMRX(HF)}$	Common mode interference beyond 450 MHz	—	—	—	200	mVpp
$\Delta V_{CMRX(LF)}$	Common mode interference between 50 MHz and 450 MHz	—	-50	—	50	mVpp
C_{CM}	Common mode termination	—	—	—	60	pF
LP Line Receiver AC Specifications						
e_{SPIKE}	Input pulse rejection	—	—	—	300	Vps
T_{MIN}	Minimum pulse response	—	50	—	—	ns
V_{INT}	Pk-to-Pk interference voltage	—	—	—	400	mV
f_{INT}	Interference frequency	—	450	—	—	MHz
Model Parameters used for Driver Load switching performance evaluation						
C_{PAD}	Equivalent Single ended I/O PAD capacitance.	—	—	—	1	pF
C_{PIN}	Equivalent Single ended Package + PCB capacitance.	—	—	—	2	pF

4.11.17.1.1 SATA PHY Transmitter Characteristics

Table 81 provides specifications for SATA PHY transmitter characteristics.

Table 81. SATA PHY Transmitter Characteristics

Parameters	Symbol	Min	Typ	Max	Unit
Transmit common mode voltage	V_{CTM}	0.4	—	0.6	V
Transmitter pre-emphasis accuracy (measured change in de-emphasized bit)	—	−0.5	—	0.5	dB

4.11.17.1.2 SATA PHY Receiver Characteristics

Table 82 provides specifications for SATA PHY receiver characteristics.

Table 82. SATA PHY Receiver Characteristics

Parameters	Symbol	Min	Typ	Max	Unit
Minimum Rx eye height (differential peak-to-peak)	$V_{MIN_RX_EYE_HEIGHT}$	175	—	—	mV
Tolerance	PPM	−400	—	400	ppm

4.11.17.2 SATA_REXT Reference Resistor Connection

The impedance calibration process requires connection of reference resistor 191 Ω 1% precision resistor on SATA_REXT pad to ground.

Resistor calibration consists of learning which state of the internal Resistor Calibration register causes an internal, digitally trimmed calibration resistor to best match the impedance applied to the SATA_REXT pin. The calibration register value is then supplied to all Tx and Rx termination resistors.

During the calibration process (for a few tens of microseconds), up to 0.3 mW can be dissipated in the external SATA_REXT resistor. At other times, no power is dissipated by the SATA_REXT resistor.

4.11.18 SCAN JTAG Controller (SJC) Timing Parameters

Figure 90 depicts the SJC test clock input timing. Figure 91 depicts the SJC boundary scan timing. Figure 92 depicts the SJC test access port. Figure 93 depicts the JTAG_TRST_B timing. Signal parameters are listed in Table 83.

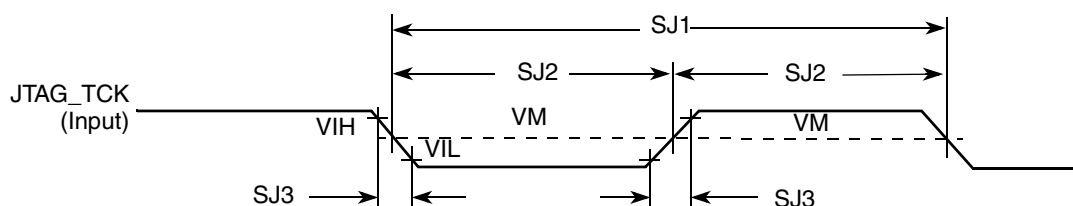


Figure 90. Test Clock Input Timing Diagram

4.11.20 SSI Timing Parameters

This section describes the timing parameters of the SSI module. The connectivity of the serial synchronous interfaces are summarized in [Table 85](#).

Table 85. AUDMUX Port Allocation

Port	Signal Nomenclature	Type and Access
AUDMUX port 1	SSI 1	Internal
AUDMUX port 2	SSI 2	Internal
AUDMUX port 3	AUD3	External – AUD3 I/O
AUDMUX port 4	AUD4	External – EIM or CSPI1 I/O through IOMUXC
AUDMUX port 5	AUD5	External – EIM or SD1 I/O through IOMUXC
AUDMUX port 6	AUD6	External – EIM or DISP2 through IOMUXC
AUDMUX port 7	SSI 3	Internal

NOTE

The terms WL and BL used in the timing diagrams and tables refer to Word Length (WL) and Bit Length (BL).

4.11.20.1 SSI Transmitter Timing with Internal Clock

[Figure 96](#) depicts the SSI transmitter internal clock timing and [Table 86](#) lists the timing parameters for the SSI transmitter internal clock.

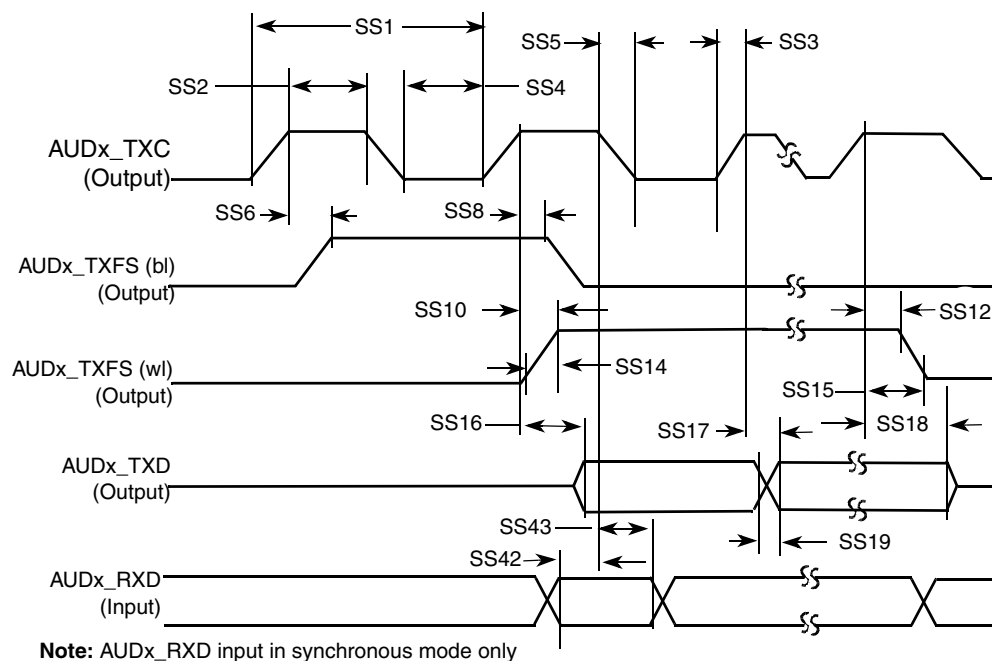


Figure 96. SSI Transmitter Internal Clock Timing Diagram

4.11.23 USB PHY Parameters

This section describes the USB-OTG PHY and the USB Host port PHY parameters.

The USB PHY meets the electrical compliance requirements defined in the Universal Serial Bus Revision 2.0 OTG, USB Host with the amendments below ([On-The-Go and Embedded Host Supplement to the USB Revision 2.0 Specification](#) is not applicable to Host port).

- USB ENGINEERING CHANGE NOTICE
 - Title: 5V Short Circuit Withstand Requirement Change
 - Applies to: Universal Serial Bus Specification, Revision 2.0
- Errata for USB Revision 2.0 April 27, 2000 as of 12/7/2000
- USB ENGINEERING CHANGE NOTICE
 - Title: Pull-up/Pull-down resistors
 - Applies to: Universal Serial Bus Specification, Revision 2.0
- USB ENGINEERING CHANGE NOTICE
 - Title: Suspend Current Limit Changes
 - Applies to: Universal Serial Bus Specification, Revision 2.0
- USB ENGINEERING CHANGE NOTICE
 - Title: USB 2.0 Phase Locked SOFs
 - Applies to: Universal Serial Bus Specification, Revision 2.0
- On-The-Go and Embedded Host Supplement to the USB Revision 2.0 Specification
 - Revision 2.0 plus errata and ecn June 4, 2010
- Battery Charging Specification (available from USB-IF)
 - Revision 1.2, December 7, 2010
 - Portable device only

6.2.2 21 x 21 mm Ground, Power, Sense, and Reference Contact Assignments

Table 99 shows the device connection list for ground, power, sense, and reference contact signals.

Table 99. 21 x 21 mm Supplies Contact Assignment

Supply Rail Name	Ball(s) Position(s)	Remark
CSI_REXT	D4	—
DRAM_VREF	AC2	—
DSI_REXT	G4	—
FA_ANA	A5	—
GND	A13, A25, A4, A8, AA10, AA13, AA16, AA19, AA22, AD4, D3, F8, J15, L10, M15, P15, T15, U8, W17, AA7, AD7, D6, G10, J18, L12, M18, P18, T17, V19, W18, AB24, AE1, D8, G19, J2, L15, M8, P8, T19, V8, W19, AB3, AE25, E5, G3, J8, L18, N10, R12, T8, W10, W3, AD10, B4, E6, H12, K10, L2, N15, R15, U11, W11, W7, AD13, C1, E7, H15, K12, L5, N18, R17, U12, W12, W8, AD16, C10, F5, H18, K15, L8, N8, R8, U15, W13, W9, AD19, C4, F6, H8, K18, M10, P10, T11, U17, W15, Y24, AD22, C6, F7, J12, K8, M12, P12, T12, U19, W16, Y5	—
GPANAIO	C8	—
HDMI_DDCCEC	K2	Analog ground reference for the Hot Plug detect signal
HDMI_REF	J1	—
HDMI_VP	L7	—
HDMI_VPH	M7	—
NVCC_CSI	N7	Supply of the camera sensor interface
NVCC_DRAM	R18, T18, U18, V10, V11, V12, V13, V14, V15, V16, V17, V18, V9	Supply of the DDR interface
NVCC_EIM0	K19	Supply of the EIM interface
NVCC_EIM1	L19	Supply of the EIM interface
NVCC_EIM2	M19	Supply of the EIM interface
NVCC_ENET	R19	Supply of the ENET interface
NVCC_GPIO	P7	Supply of the GPIO interface
NVCC_JTAG	J7	Supply of the JTAG tap controller interface
NVCC_LCD	P19	Supply of the LCD interface
NVCC_LVDS2P5	V7	Supply of the LVDS display interface and DDR pre-drivers. Even if the LVDS interface is not used, this supply must remain powered.
NVCC_MIPI	K7	Supply of the MIPI interface

Table 100. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition ¹			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value ²
DRAM_D11	AE7	NVCC_DRAM	DDR	ALT0	DRAM_DATA11	Input	PU (100K)
DRAM_D12	AB5	NVCC_DRAM	DDR	ALT0	DRAM_DATA12	Input	PU (100K)
DRAM_D13	AC5	NVCC_DRAM	DDR	ALT0	DRAM_DATA13	Input	PU (100K)
DRAM_D14	AB6	NVCC_DRAM	DDR	ALT0	DRAM_DATA14	Input	PU (100K)
DRAM_D15	AC7	NVCC_DRAM	DDR	ALT0	DRAM_DATA15	Input	PU (100K)
DRAM_D16	AB7	NVCC_DRAM	DDR	ALT0	DRAM_DATA16	Input	PU (100K)
DRAM_D17	AA8	NVCC_DRAM	DDR	ALT0	DRAM_DATA17	Input	PU (100K)
DRAM_D18	AB9	NVCC_DRAM	DDR	ALT0	DRAM_DATA18	Input	PU (100K)
DRAM_D19	Y9	NVCC_DRAM	DDR	ALT0	DRAM_DATA19	Input	PU (100K)
DRAM_D2	AC4	NVCC_DRAM	DDR	ALT0	DRAM_DATA02	Input	PU (100K)
DRAM_D20	Y7	NVCC_DRAM	DDR	ALT0	DRAM_DATA20	Input	PU (100K)
DRAM_D21	Y8	NVCC_DRAM	DDR	ALT0	DRAM_DATA21	Input	PU (100K)
DRAM_D22	AC8	NVCC_DRAM	DDR	ALT0	DRAM_DATA22	Input	PU (100K)
DRAM_D23	AA9	NVCC_DRAM	DDR	ALT0	DRAM_DATA23	Input	PU (100K)
DRAM_D24	AE9	NVCC_DRAM	DDR	ALT0	DRAM_DATA24	Input	PU (100K)
DRAM_D25	Y10	NVCC_DRAM	DDR	ALT0	DRAM_DATA25	Input	PU (100K)
DRAM_D26	AE11	NVCC_DRAM	DDR	ALT0	DRAM_DATA26	Input	PU (100K)
DRAM_D27	AB11	NVCC_DRAM	DDR	ALT0	DRAM_DATA27	Input	PU (100K)
DRAM_D28	AC9	NVCC_DRAM	DDR	ALT0	DRAM_DATA28	Input	PU (100K)
DRAM_D29	AD9	NVCC_DRAM	DDR	ALT0	DRAM_DATA29	Input	PU (100K)
DRAM_D3	AA5	NVCC_DRAM	DDR	ALT0	DRAM_DATA03	Input	PU (100K)
DRAM_D30	AD11	NVCC_DRAM	DDR	ALT0	DRAM_DATA30	Input	PU (100K)
DRAM_D31	AC11	NVCC_DRAM	DDR	ALT0	DRAM_DATA31	Input	PU (100K)
DRAM_D32	AA17	NVCC_DRAM	DDR	ALT0	DRAM_DATA32	Input	PU (100K)
DRAM_D33	AA18	NVCC_DRAM	DDR	ALT0	DRAM_DATA33	Input	PU (100K)
DRAM_D34	AC18	NVCC_DRAM	DDR	ALT0	DRAM_DATA34	Input	PU (100K)
DRAM_D35	AE19	NVCC_DRAM	DDR	ALT0	DRAM_DATA35	Input	PU (100K)
DRAM_D36	Y17	NVCC_DRAM	DDR	ALT0	DRAM_DATA36	Input	PU (100K)
DRAM_D37	Y18	NVCC_DRAM	DDR	ALT0	DRAM_DATA37	Input	PU (100K)
DRAM_D38	AB19	NVCC_DRAM	DDR	ALT0	DRAM_DATA38	Input	PU (100K)
DRAM_D39	AC19	NVCC_DRAM	DDR	ALT0	DRAM_DATA39	Input	PU (100K)
DRAM_D4	AC1	NVCC_DRAM	DDR	ALT0	DRAM_DATA04	Input	PU (100K)
DRAM_D40	Y19	NVCC_DRAM	DDR	ALT0	DRAM_DATA40	Input	PU (100K)
DRAM_D41	AB20	NVCC_DRAM	DDR	ALT0	DRAM_DATA41	Input	PU (100K)
DRAM_D42	AB21	NVCC_DRAM	DDR	ALT0	DRAM_DATA42	Input	PU (100K)
DRAM_D43	AD21	NVCC_DRAM	DDR	ALT0	DRAM_DATA43	Input	PU (100K)

Table 100. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition ¹			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value ²
DRAM_D44	Y20	NVCC_DRAM	DDR	ALT0	DRAM_DATA44	Input	PU (100K)
DRAM_D45	AA20	NVCC_DRAM	DDR	ALT0	DRAM_DATA45	Input	PU (100K)
DRAM_D46	AE21	NVCC_DRAM	DDR	ALT0	DRAM_DATA46	Input	PU (100K)
DRAM_D47	AC21	NVCC_DRAM	DDR	ALT0	DRAM_DATA47	Input	PU (100K)
DRAM_D48	AC22	NVCC_DRAM	DDR	ALT0	DRAM_DATA48	Input	PU (100K)
DRAM_D49	AE22	NVCC_DRAM	DDR	ALT0	DRAM_DATA49	Input	PU (100K)
DRAM_D5	AD1	NVCC_DRAM	DDR	ALT0	DRAM_DATA05	Input	PU (100K)
DRAM_D50	AE24	NVCC_DRAM	DDR	ALT0	DRAM_DATA50	Input	PU (100K)
DRAM_D51	AC24	NVCC_DRAM	DDR	ALT0	DRAM_DATA51	Input	PU (100K)
DRAM_D52	AB22	NVCC_DRAM	DDR	ALT0	DRAM_DATA52	Input	PU (100K)
DRAM_D53	AC23	NVCC_DRAM	DDR	ALT0	DRAM_DATA53	Input	PU (100K)
DRAM_D54	AD25	NVCC_DRAM	DDR	ALT0	DRAM_DATA54	Input	PU (100K)
DRAM_D55	AC25	NVCC_DRAM	DDR	ALT0	DRAM_DATA55	Input	PU (100K)
DRAM_D56	AB25	NVCC_DRAM	DDR	ALT0	DRAM_DATA56	Input	PU (100K)
DRAM_D57	AA21	NVCC_DRAM	DDR	ALT0	DRAM_DATA57	Input	PU (100K)
DRAM_D58	Y25	NVCC_DRAM	DDR	ALT0	DRAM_DATA58	Input	PU (100K)
DRAM_D59	Y22	NVCC_DRAM	DDR	ALT0	DRAM_DATA59	Input	PU (100K)
DRAM_D6	AB4	NVCC_DRAM	DDR	ALT0	DRAM_DATA06	Input	PU (100K)
DRAM_D60	AB23	NVCC_DRAM	DDR	ALT0	DRAM_DATA60	Input	PU (100K)
DRAM_D61	AA23	NVCC_DRAM	DDR	ALT0	DRAM_DATA61	Input	PU (100K)
DRAM_D62	Y23	NVCC_DRAM	DDR	ALT0	DRAM_DATA62	Input	PU (100K)
DRAM_D63	W25	NVCC_DRAM	DDR	ALT0	DRAM_DATA63	Input	PU (100K)
DRAM_D7	AE4	NVCC_DRAM	DDR	ALT0	DRAM_DATA07	Input	PU (100K)
DRAM_D8	AD5	NVCC_DRAM	DDR	ALT0	DRAM_DATA08	Input	PU (100K)
DRAM_D9	AE5	NVCC_DRAM	DDR	ALT0	DRAM_DATA09	Input	PU (100K)
DRAM_DQM0	AC3	NVCC_DRAM	DDR	ALT0	DRAM_DQM0	Output	0
DRAM_DQM1	AC6	NVCC_DRAM	DDR	ALT0	DRAM_DQM1	Output	0
DRAM_DQM2	AB8	NVCC_DRAM	DDR	ALT0	DRAM_DQM2	Output	0
DRAM_DQM3	AE10	NVCC_DRAM	DDR	ALT0	DRAM_DQM3	Output	0
DRAM_DQM4	AB18	NVCC_DRAM	DDR	ALT0	DRAM_DQM4	Output	0
DRAM_DQM5	AC20	NVCC_DRAM	DDR	ALT0	DRAM_DQM5	Output	0
DRAM_DQM6	AD24	NVCC_DRAM	DDR	ALT0	DRAM_DQM6	Output	0
DRAM_DQM7	Y21	NVCC_DRAM	DDR	ALT0	DRAM_DQM7	Output	0
DRAM_RAS	AB15	NVCC_DRAM	DDR	ALT0	DRAM_RAS_B	Output	0
DRAM_RESET	Y6	NVCC_DRAM	DDR	ALT0	DRAM_RESET	Output	0
DRAM_SDBA0	AC15	NVCC_DRAM	DDR	ALT0	DRAM_SDBA0	Output	0

Table 102. 21 x 21 mm, 0.8 mm Pitch Ball Map (continued)

AE	AD	AC	
GND	DRAM_D5	DRAM_D4	1
DRAM_D1	DRAM_D0	DRAM_VREF	2
DRAM_SDQS0	DRAM_SDQS0_B	DRAM_DQM0	3
DRAM_D7	GND	DRAM_D2	4
DRAM_D9	DRAM_D8	DRAM_D13	5
DRAM_SDQS1_B	DRAM_SDQS1	DRAM_DQM1	6
DRAM_D11	GND	DRAM_D15	7
DRAM_SDQS2_B	DRAM_SDQS2	DRAM_D22	8
DRAM_D24	DRAM_D29	DRAM_D28	9
DRAM_DQM3	GND	DRAM_SDQS3	10
DRAM_D26	DRAM_D30	DRAM_D31	11
DRAM_A9	DRAM_A12	DRAM_A11	12
DRAM_A5	GND	DRAM_A6	13
DRAM_SDCLK_1_B	DRAM_SDCLK_1	DRAM_A0	14
DRAM_SDCLK_0_B	DRAM_SDCLK_0	DRAM_SDBA0	15
DRAM_CAS	GND	DRAM_SDODT0	16
ZQPAD	DRAM_CS1	DRAM_A13	17
DRAM_SDQS4_B	DRAM_SDQS4	DRAM_D34	18
DRAM_D35	GND	DRAM_D39	19
DRAM_SDQS5_B	DRAM_SDQS5	DRAM_DQM5	20
DRAM_D46	DRAM_D43	DRAM_D47	21
DRAM_D49	GND	DRAM_D48	22
DRAM_SDQS6_B	DRAM_SDQS6	DRAM_D53	23
DRAM_D50	DRAM_DQM6	DRAM_D51	24
GND	DRAM_D54	DRAM_D55	25